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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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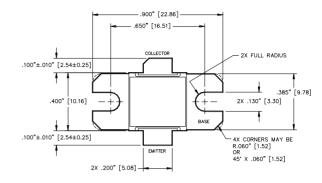
# Radar Pulsed Power Transistor 130 W, 2.7—-2.9 GHz, 100 µs Pulse, 10% Duty

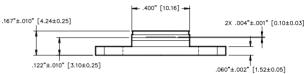
Rev. V1

#### **Features**

- · NPN silicon microwave power transistors
- Common base configuration
- · Broadband Class C operation
- · High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

### **Outline Drawing**





UNLESS OTHERWISE NOTED, TOLERANCES ARE INCHES ±.005" [MILLIMETERS ±0.13MM]

## Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V <sub>CES</sub>	63	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	Ic	12.5	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	575	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	TJ	200	°C

# Electrical Specifications: $T_C = 25 \pm 5^{\circ}C$ (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 40mA		BV <sub>CES</sub>	63	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 36V		I <sub>CES</sub>	-	7.5	mA
Thermal Resistance	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	R <sub>TH(JC)</sub>	-	0.3	°C/W
Input Power	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	P <sub>IN</sub>	-	23	W
Power Gain	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	$G_{P}$	7.0	-	dB
Collector Efficiency	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	ης	40	-	%
Input Return Loss	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	RL	-	-10	dB
Pulse Droop	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	Droop	-	0.5	dB
Load Mismatch Tolerance	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	VSWR-T	-	2:1	-
Load Mismatch Stability	Vcc = 36V, Pout = 130W	F = 2.7, 2.8, 2.9 GHz	VSWR-S	-	1.5:1	-



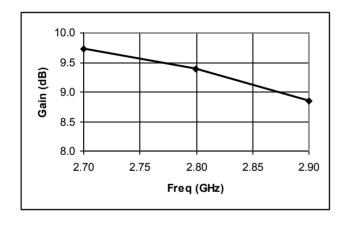
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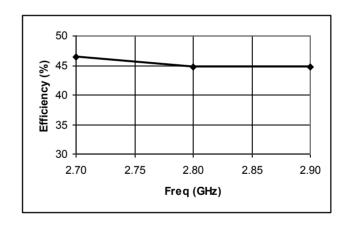
## **Typical RF Performance**

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (2:1)
2.7	13.9	130	9.73	7.78	46.4	-11.4	S	Р
2.8	15.0	130	9.38	8.07	44.8	-13.6	S	Р
2.9	17.0	130	8.85	8.07	44.8	-13.8	S	Р

# Gain vs. Frequency

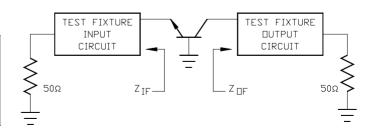


## **Collector Efficiency vs. Frequency**



### **RF Test Fixture Impedance**

F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
2.7	5.5 - j9.1	1.9 - j5.6
2.8	5.25 - j8.8	1.75 - j5.2
2.9	5.05 - j8.3	1.6 - j4.8

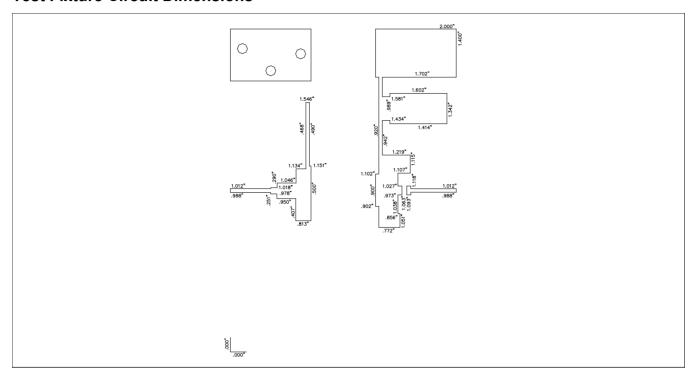




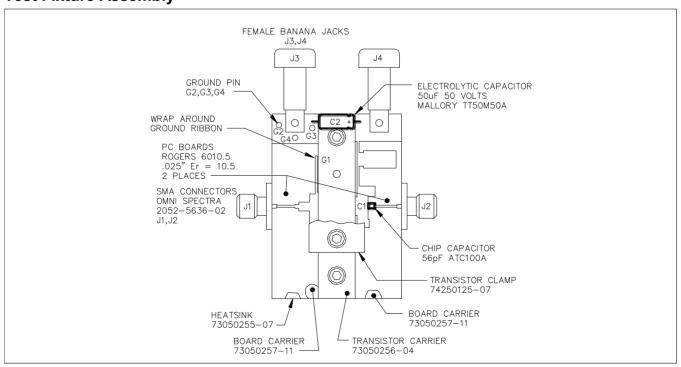
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#### **Test Fixture Circuit Dimensions**



## **Test Fixture Assembly**



# PH2729-130M



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